

AD8663/AD8667/AD8669

FEATURES

- Low offset voltage: 175 μV maximum @ $V_{\text{SY}} = 5\text{ V}$
- Low supply current: 275 μA maximum per amplifier
- Single-supply operation: 5 V to 16 V
- Low noise: 23 $\text{nV}/\sqrt{\text{Hz}}$
- Low input bias current: 300 fA
- Unity-gain stable
- Small packages available
 - 3 mm \times 3 mm, 8-lead LFCSP
 - 8-lead MSOP
- Other packages
 - 8-lead SOIC
 - 14-lead SOIC
 - 14-lead TSSOP

APPLICATIONS

- Sensor front ends
- Transimpedance amplifiers
- Electrometer applications
- Photodiode amplification
- Low power ADC drivers
- Medical diagnostic instruments
- pH and ORP meters and probes
- DAC or REF buffers

GENERAL DESCRIPTION

The AD866x are rail-to-rail output amplifiers that use the Analog Devices, Inc., patented DigiTrim[®] trimming technique to achieve low offset voltage. The AD866x feature an extended operating range with supply voltages up to 16 V. They also feature low input bias current, low input offset voltage, and low current noise.

The combination of low offset, very low input bias current, and a wide supply range makes these amplifiers useful in a wide variety of applications usually associated with higher priced JFET amplifiers. Systems using high impedance sensors, such as photodiodes, benefit from the combination of low input bias current, low noise, low offset, and wide bandwidth.

The ability to operate the device for single (5 V to 16 V) or dual supplies ($\pm 2.5\text{ V}$ to $\pm 8\text{ V}$) supports many applications. The rail-to-rail outputs provide increased dynamic range to drive low

PIN CONFIGURATIONS

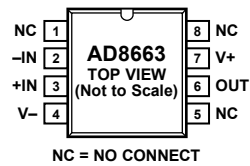


Figure 1. 8-Lead SOIC (R-8)

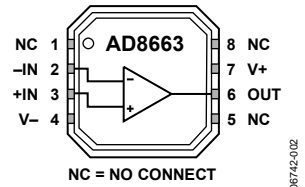


Figure 2. 8-Lead LFCSP (CP-8-2)

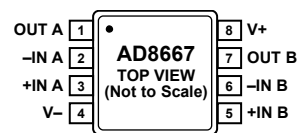


Figure 3. 8-Lead MSOP (RM-8),
8-Lead SOIC (R-8)

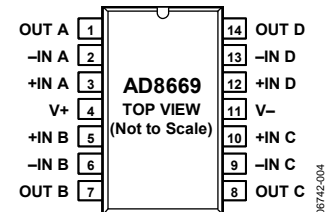


Figure 4. 14-Lead SOIC (R-14),
14-Lead TSSOP (RU-14)

frequency data converters. The low bias current drift is well-suited for precision I-to-V converters. The combination of precision offset, offset drift, and low noise also make the op amps ideal for gain, dc offset adjust, and active filter in both instrumentation and medical applications. These low power op amps can be used in IR thermometers, pH and ORP instruments, pressure transducer front ends, and other sensor signal conditioning circuits that are used in remote or wireless applications.

The AD8663/AD8667/AD8669 are specified over the extended industrial temperature range of -40°C to $+125^{\circ}\text{C}$. The single AD8663 is available in a narrow 8-lead SOIC package and a very thin, 8-lead LFCSP. The dual AD8667 is available in a narrow 8-lead SOIC package and an 8-lead MSOP. The quad AD8669 is available in a 14-lead SOIC and 14-lead small TSSOP.

Rev. B

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REVISION HISTORY

1/08—Rev. A to Rev. B

| | |
|---|-----------|
| Added TSSOP | Universal |
| Change to Table 4 | 5 |
| Changes to Figure 8 and Figure 9..... | 6 |
| Changes to Figure 23 and Figure 26..... | 9 |
| Updated Outline Dimensions | 13 |
| Changes to Ordering Guide | 15 |

10/07—Rev. 0 to Rev. A

| | |
|---|-----------|
| Added AD8667 and AD8669 | Universal |
| Changes to Features..... | 1 |
| Changes to General Description | 1 |
| Inserted Figure 3 and Figure 4..... | 1 |
| Changes to Table 1, Power Supply Section..... | 3 |
| Changes to Table 2..... | 4 |
| Reformatted Typical Performance Characteristics Section | 6 |
| Changes to Figure 5..... | 6 |
| Changes to Figure 13..... | 7 |
| Changes to Figure 17 and Figure 20..... | 8 |
| Inserted Figure 35 Through Figure 39..... | 11 |
| Inserted Figure 40 and Figure 41 | 12 |
| Updated Outline Dimensions | 13 |
| Changes to Ordering Guide | 15 |

7/07—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS

$V_{SY} = 5.0\text{ V}$, $V_{CM} = V_{SY}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|------------------|--|------|---------|-----|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $V_{CM} = V_{SY}/2$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 30 | 175 | μV |
| Input Bias Current | I_B | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.3 | 450 | μV |
| | | | | | 45 | pA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.2 | 105 | pA |
| | | | | | 35 | pA |
| Input Voltage Range | | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 0.2 | | 65 | pA |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = 0.2\text{ V to }3.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 76 | 100 | dB |
| | | | | 76 | 100 | dB |
| Large Signal Voltage Gain | A_{VO} | $R_L = 100\text{ k}\Omega$, $V_{OUT} = 0.5\text{ V to }4.5\text{ V}$ $R_L = 2\text{ k}\Omega$, $V_{OUT} = 0.5\text{ V to }4.5\text{ V}$ | | 115 | 140 | dB |
| | | | | 106 | 114 | dB |
| Offset Voltage Drift | TCV_{OS} | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 1.5 | 5 | $\mu\text{V}/^\circ\text{C}$ |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $I_L = 100\text{ }\mu\text{A}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 4.95 | 4.97 | | V |
| | | | 4.90 | | | V |
| Output Voltage High | V_{OH} | $I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 4.65 | 4.80 | | V |
| | | | 4.60 | | | V |
| Output Voltage Low | V_{OL} | $I_L = 100\text{ }\mu\text{A}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 17 | 25 | mV |
| | | | | | 35 | mV |
| Output Voltage Low | V_{OL} | $I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 150 | 200 | mV |
| | | | | | 250 | mV |
| Short-Circuit Current | I_{SC} | | | ± 7 | | mA |
| Closed-Loop Output Impedance | Z_{OUT} | $f = 100\text{ kHz}$, $A_V = 1$ | | 120 | | Ω |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_{SY} = 5\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 95 | 105 | | dB |
| | | | 95 | | | dB |
| Supply Current per Amplifier | I_{SY} | $V_{OUT} = V_{SY}/2$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 210 | 275 | μA |
| | | | | | 325 | μA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2\text{ k}\Omega$ | | 0.26 | | $\text{V}/\mu\text{s}$ |
| Gain Bandwidth Product | GBP | $C_L = 20\text{ pF}$ | | 520 | | kHz |
| Phase Margin | Φ_M | $C_L = 20\text{ pF}$ | | 60 | | Degrees |
| NOISE PERFORMANCE | | | | | | |
| Peak-to-Peak Noise | $e_n\text{ p-p}$ | $f = 0.1\text{ Hz to }10\text{ Hz}$ | | 2.5 | | $\mu\text{V p-p}$ |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ | | 23 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| | | $f = 10\text{ kHz}$ | | 21 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 1\text{ kHz}$ | | 0.05 | | $\text{pA}/\sqrt{\text{Hz}}$ |

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$V_{SY} = 16.0\text{ V}$, $V_{CM} = V_{SY}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|------------------|--|-------|----------|------|--|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $V_{CM} = V_{SY}/2$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 40 | 300 | μV |
| Input Bias Current | I_B | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.3 | 45 | μV pA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.2 | 120 | pA pA |
| Input Voltage Range | | | 0.2 | | 14.5 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = 0.2\text{ V to }14.5\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 87 | 109 | | dB |
| Large Signal Voltage Gain | A_{VO} | $R_L = 100\text{ k}\Omega$, $V_{OUT} = 0.5\text{ V to }15.5\text{ V}$ $R_L = 2\text{ k}\Omega$, $V_{OUT} = 0.5\text{ V to }15.5\text{ V}$ | 115 | 140 | | dB |
| Offset Voltage Drift | TCV_{OS} | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 1.5 | 5 | $\mu\text{V}/^\circ\text{C}$ |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $I_L = 100\text{ }\mu\text{A}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 15.95 | 15.98 | | V |
| Output Voltage High | V_{OH} | $I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 15.90 | 15.92 | | V |
| Output Voltage Low | V_{OL} | $I_L = 100\text{ }\mu\text{A}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 15.85 | | 25 | V |
| Output Voltage Low | V_{OL} | $I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 15.80 | | 35 | V |
| Short-Circuit Current | I_{SC} | | | ± 50 | | mV |
| Closed-Loop Output Impedance | Z_{OUT} | $f = 100\text{ kHz}$, $A_V = 1$ | | 100 | | mV |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_{SY} = 5\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 95 | 105 | | dB |
| Supply Current per Amplifier | I_{SY} | $V_{OUT} = V_{SY}/2$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 230 | 285 | dB |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2\text{ k}\Omega$ | | 0.3 | | μA |
| Gain Bandwidth Product | GBP | $C_L = 20\text{ pF}$ | | 540 | | $\text{V}/\mu\text{s}$ |
| Phase Margin | Φ_M | $C_L = 20\text{ pF}$ | | 64 | | kHz |
| NOISE PERFORMANCE | | | | | | |
| Peak-to-Peak Noise | $e_n\text{ p-p}$ | $f = 0.1\text{ Hz to }10\text{ Hz}$ | | 2.5 | | Degrees |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ $f = 10\text{ kHz}$ | | 23 | | $\mu\text{V p-p}$ $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 1\text{ kHz}$ | | 21 | | $\text{nV}/\sqrt{\text{Hz}}$ $\text{pA}/\sqrt{\text{Hz}}$ |

ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
|--------------------------------------|--------------------|
| Supply Voltage | 18 V |
| Input Voltage | -0.1 V to V_{SY} |
| Differential Input Voltage | 18 V |
| Output Short-Circuit Duration to GND | Indefinite |
| Storage Temperature Range | -60°C to +150°C |
| Operating Temperature Range | -40°C to +125°C |
| Junction Temperature Range | -65°C to +150°C |
| Lead Temperature, Soldering (60 sec) | 300°C |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Resistance

| Package Type | θ_{JA} | θ_{JC} | Unit |
|-----------------------|-----------------|-----------------|------|
| 8-Lead SOIC (R-8) | 121 | 43 | °C/W |
| 8-Lead LFCSP (CP-8-2) | 75 ¹ | 18 ¹ | °C/W |
| 8-Lead MSOP (RM-8) | 145 | 45 | °C/W |
| 14-Lead SOIC (R-14) | 90 | 45 | °C/W |
| 14-Lead TSSOP (RU-14) | 180 | 35 | °C/W |

¹ Exposed pad soldered to application board.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

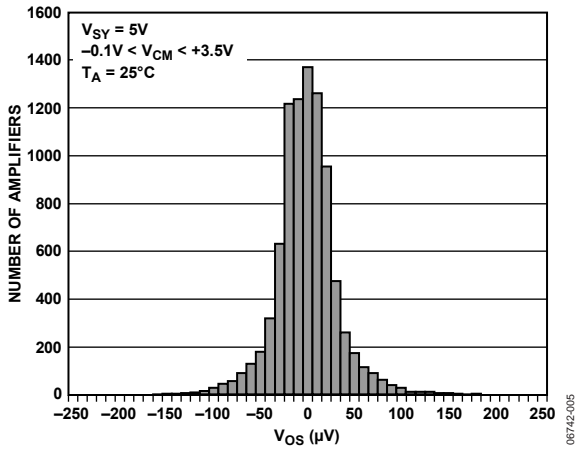


Figure 5. Input Offset Voltage Distribution

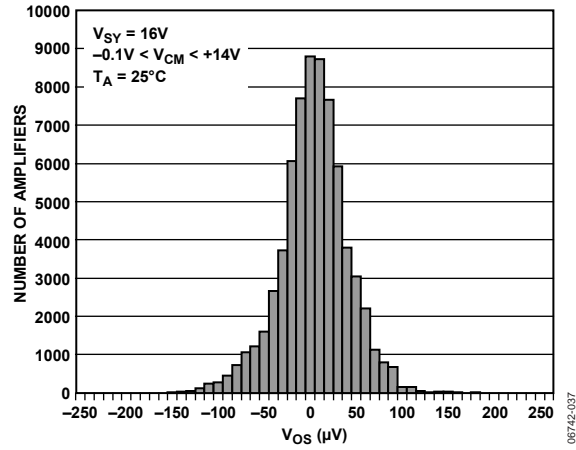


Figure 8. Input Offset Voltage Distribution

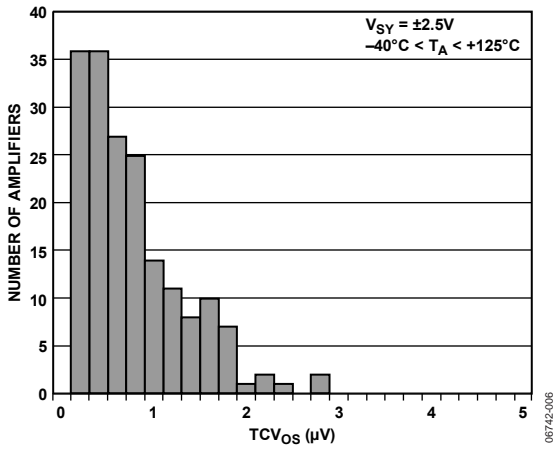


Figure 6. Offset Voltage Drift Distribution

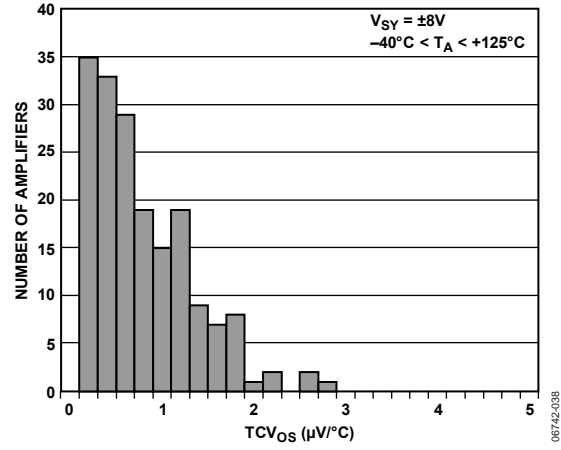


Figure 9. Offset Voltage Drift Distribution

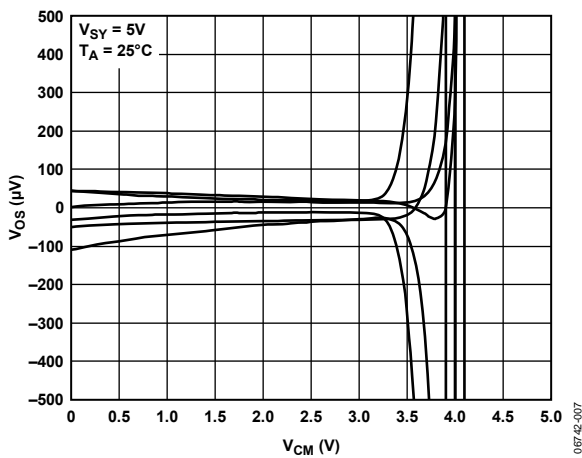


Figure 7. Input Offset Voltage vs. Common-Mode Voltage

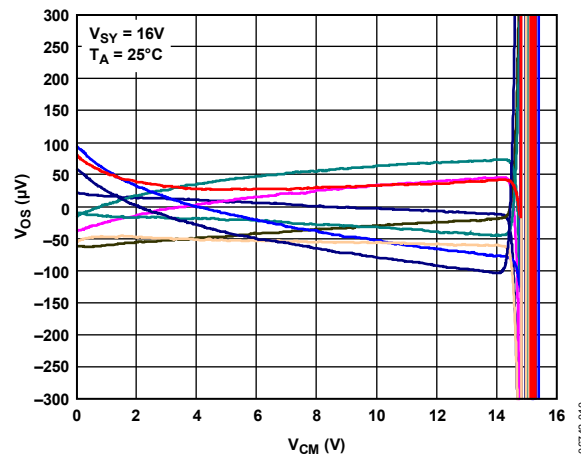


Figure 10. Input Offset Voltage vs. Common-Mode Voltage

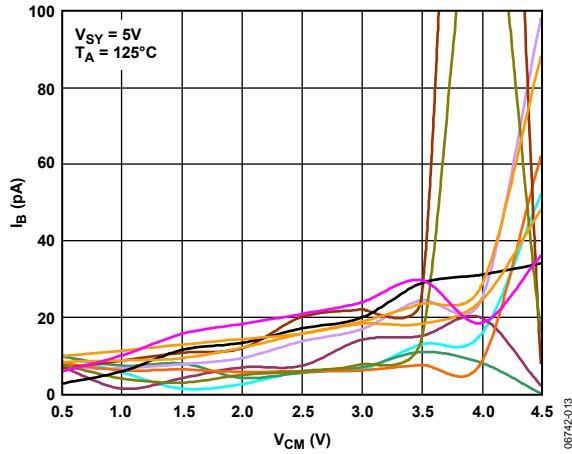


Figure 11. Input Bias Current vs. Common-Mode Voltage at 125°C

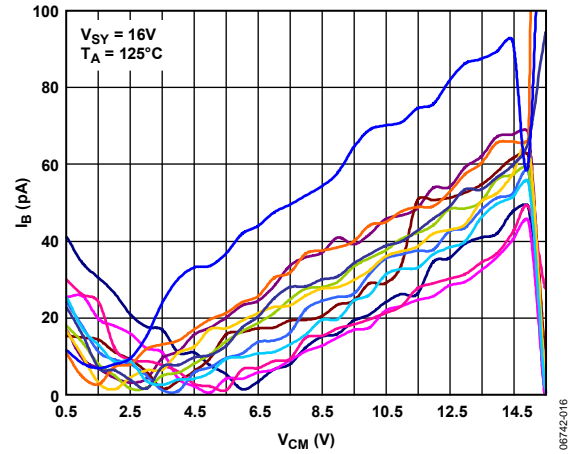


Figure 14. Input Bias Current vs. Common-Mode Voltage at 125°C

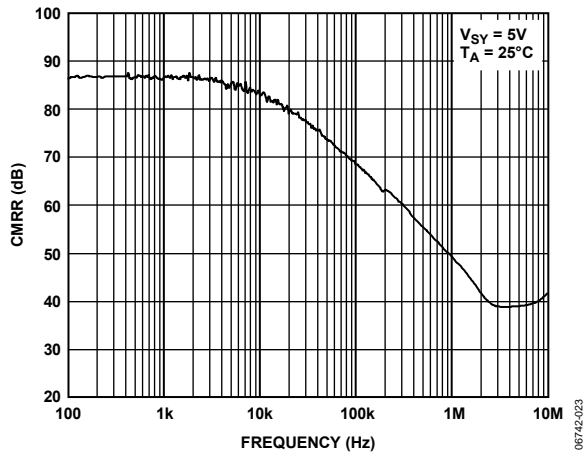


Figure 12. CMRR vs. Frequency, $V_{SY} = 5V$

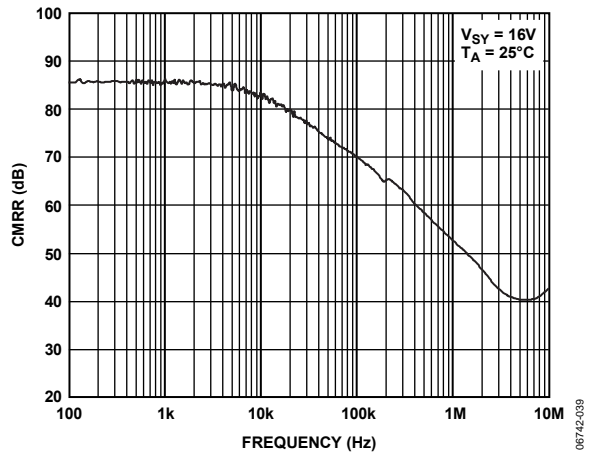


Figure 15. CMRR vs. Frequency, $V_{SY} = 16V$

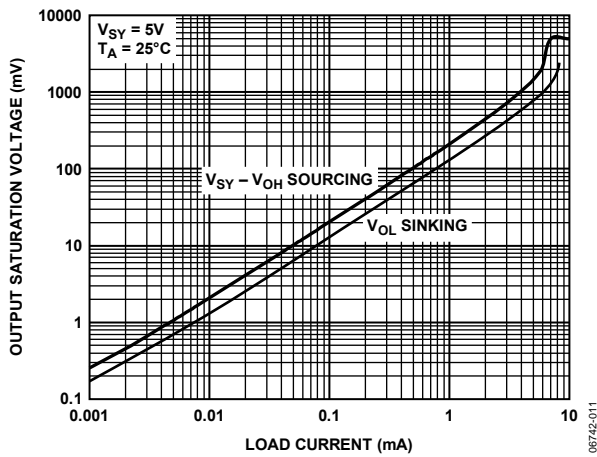


Figure 13. Output Swing Saturation Voltage vs. Load Current

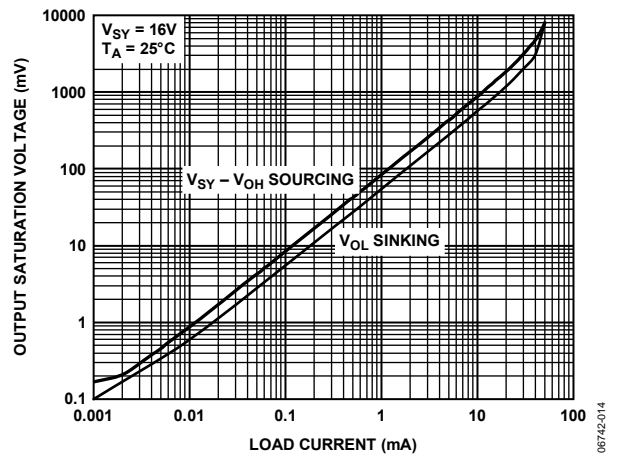


Figure 16. Output Swing Saturation Voltage vs. Load Current

AD8663/AD8667/AD8669

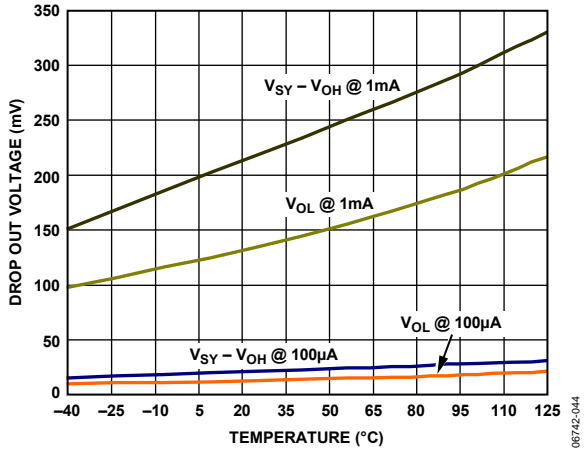


Figure 17. Output Voltage Saturation vs. Temperature

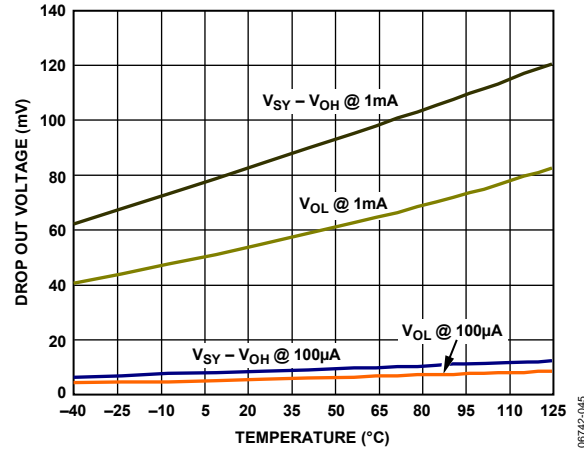


Figure 20. Output Voltage Saturation vs. Temperature

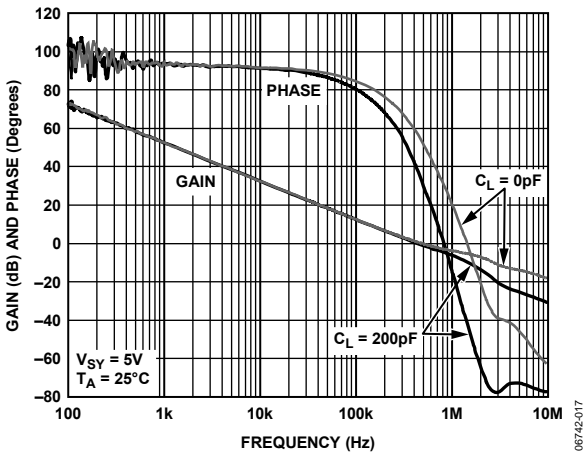


Figure 18. Open-Loop Gain and Phase Shift vs. Frequency

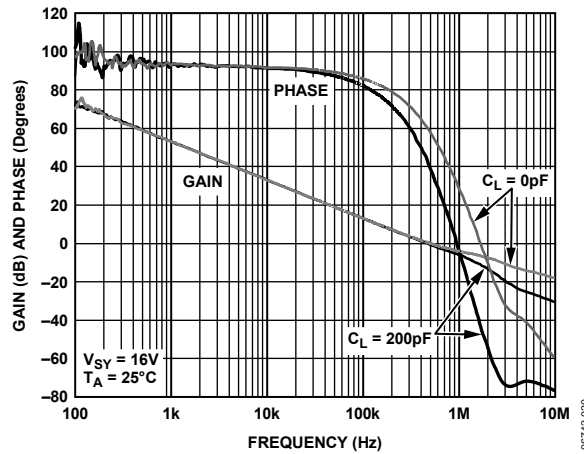


Figure 21. Open-Loop Gain and Phase Shift vs. Frequency

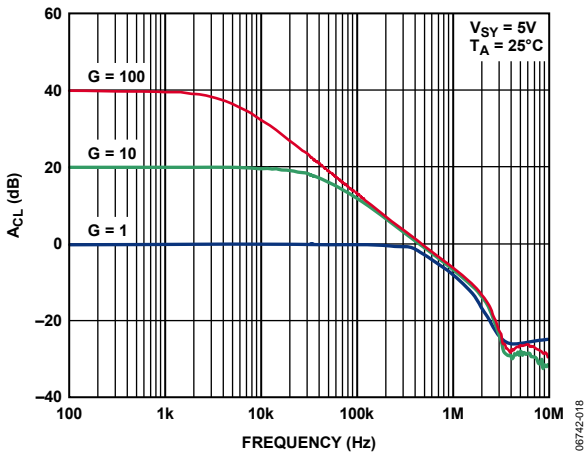


Figure 19. Closed-Loop Gain vs. Frequency

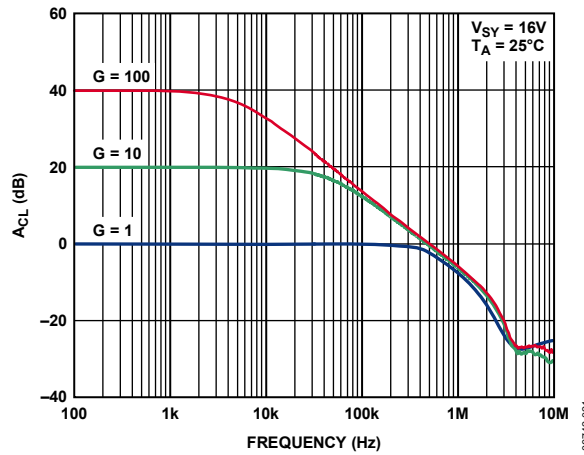


Figure 22. Closed-Loop Gain vs. Frequency, $V_{SY} = 16V$

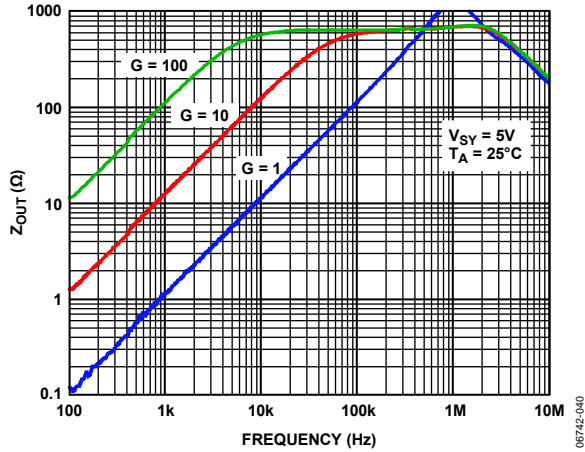


Figure 23. Closed-Loop Output Impedance vs. Frequency, $V_{SY} = 5\text{ V}$

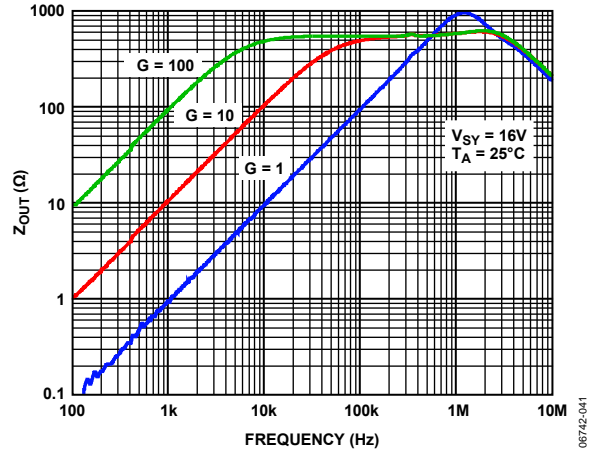


Figure 26. Closed-Loop Output Impedance vs. Frequency, $V_{SY} = 16\text{ V}$

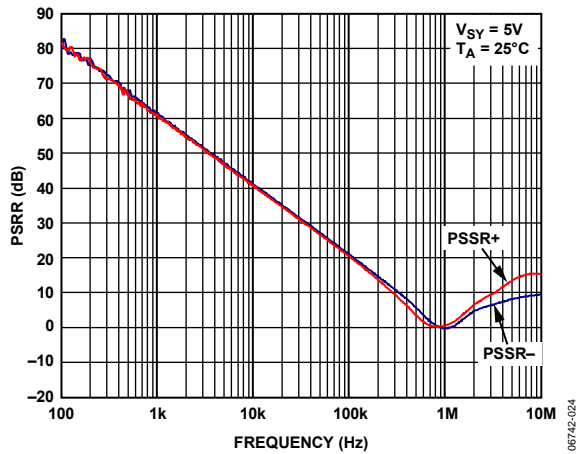


Figure 24. PSRR vs. Frequency, $V_{SY} = 5\text{ V}$

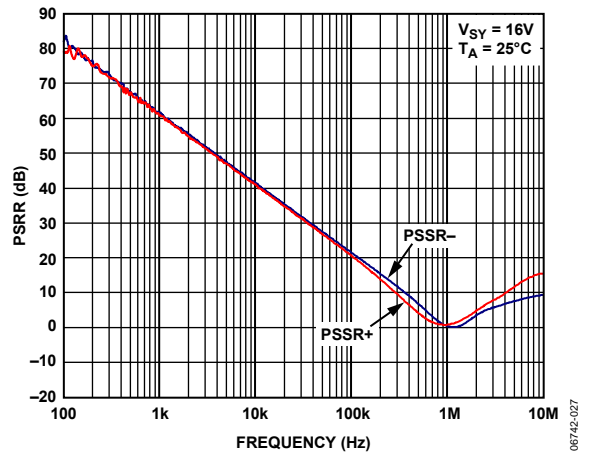


Figure 27. PSRR vs. Frequency, $V_{SY} = 16\text{ V}$

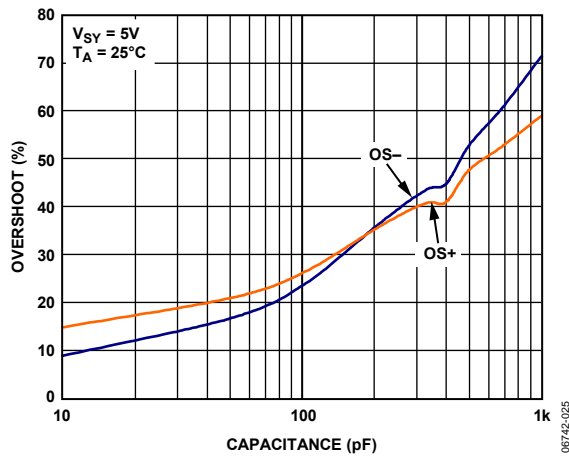


Figure 25. Small-Signal Overshoot vs. Load Capacitance, $V_{SY} = 5\text{ V}$

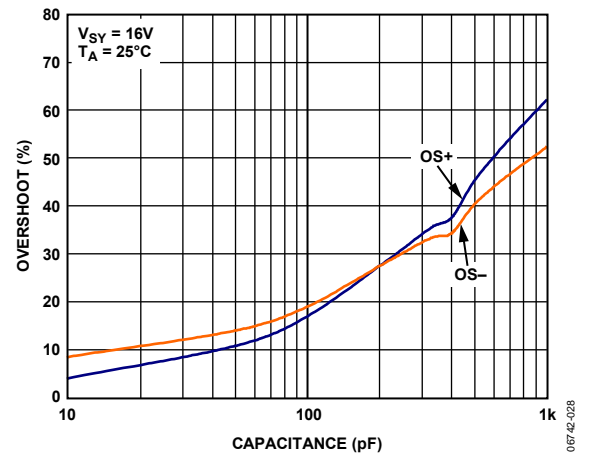


Figure 28. Small-Signal Overshoot vs. Load Capacitance, $V_{SY} = 16\text{ V}$

